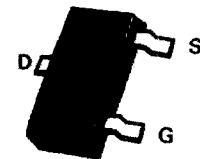


**SOT23 N-CHANNEL ENHANCEMENT
MODE VERTICAL DMOS FET**

ISSUE 2 – DECEMBER 1995

ZVN4106F

PARMARKING DETAIL - MZ



ABSOLUTE MAXIMUM RATINGS.

| PARAMETER | SYMBOL | VALUE | UNIT |
|---|----------------|-------------|-------------|
| Drain-Source Voltage | V_{DS} | 60 | V |
| Continuous Drain Current at $T_{amb}=25^{\circ}C$ | I_D | 0.2 | A |
| Pulsed Drain Current | I_{DM} | 3 | A |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Max Power Dissipation at $T_{amb}=25^{\circ}C$ | P_{tot} | 330 | mW |
| Operating and Storage Temperature Range | T_j, T_{stg} | -55 to +150 | $^{\circ}C$ |

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

| PARAMETER | SYMBOL | MIN. | MAX. | UNIT | CONDITIONS. |
|---|--------------|------|----------|----------|--|
| Drain-Source Breakdown Voltage | BV_{DSS} | 60 | | V | $I_D=1mA, V_{GS}=0V$ |
| Gate-Source Threshold Voltage | $V_{GS(th)}$ | 1.3 | 3 | V | $I_D=1mA, V_{DS}=V_{GS}$ |
| Gate-Body Leakage | I_{GSS} | | 100 | nA | $V_{GS}=\pm 20V, V_{DS}=0V$ |
| Zero Gate Voltage Drain Current | I_{DSS} | | 10 50 | μA | $V_{DS}=60V, V_{GS}=0$ $V_{DS}=48V, V_{GS}=0V, T=125^{\circ}C(2)$ |
| On-State Drain Current(1) | $I_{D(on)}$ | 1 | | A | $V_{DS}=25V, V_{GS}=10V$ |
| Static Drain-Source On-State Resistance (1) | $R_{DS(on)}$ | | 2.5 5 | Ω | $V_{GS}=10V, I_D=500mA$ $V_{GS}=5V, I_D=200mA$ |
| Forward Transconductance(1)(2) g_{fs} | | 150 | | mS | $V_{DS}=25V, I_D=250mA$ |
| Input Capacitance (2) | C_{iss} | | 35 | pF | |
| Common Source Output Capacitance (2) | C_{oss} | | 25 | pF | $V_{DS}=25V, V_{GS}=0V, f=1MHz$ |
| Reverse Transfer Capacitance (2) | C_{rss} | | 8 | pF | |
| Turn-On Delay Time (2)(3) | $T_{d(on)}$ | | 5 | ns | |
| Rise Time (2)(3) | T_r | | 7 | ns | |
| Turn-Off Delay Time (2)(3) | $T_{d(off)}$ | | 6 | ns | $V_{DD}=25V, I_D=150mA$ |
| Fall Time (2)(3) | T_f | | 8 | ns | |

(1) Measured under pulsed conditions. Width=300 μ s. Duty cycle $\leq 2\%$ (2) Sample test.

(3) Switching times measured with 500 Ω source impedance and <5ns rise time on a pulse generator
Spice parameter data is available upon request for this device

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